



PRODUCT DATASHEET



- High Power
- K1 5.3t Hump Series
- Infrared 850nm





N0F23S31

APPLICATIONS:

- Security Camera
- Motion Detection
- Night Viewer
- Surveillance

1

K1 Hump Series



FEATURES:

- Package: K1 SMT Package with Hump Shape Silicon Lens
- Forward Current: 200mA
- Forward Voltage (typ.): 1.8V
- Radiant Power (typ.): 130mW@200mA
- Colour: Infrared (IR)
- Wavelength: 840-860nm
- Viewing angle: 160°
- Materials:
 - Die: AlGaAs
 - Resin: Silicon (Water Clear)
 - L/T Finish: Ag plated
- Operating Temperature: -40~+80°C
- Storage Temperature: -40~+100°C
- Grouping parameters:
 - Forward Voltage
 - Radiant Power
 - Peak Wavelength
- Soldering methods: IR Reflow
- **Preconditioning:** MSL 3 according to J-STD020
- Packing: 26mm tape with max.500pcs/reel, ø330mm (13")



CHARACTERISTICS:

Absolute Maximum Characteristics (Ta=25°C)

Parameter	Symbol	Ratings	Unit
DC Forward Current	lF	250	mA
Reverse Voltage	V _R	5	V
Reverse Current @5V	IR	10	μΑ
Temperature Coefficient of Voltage	к	-1.2	mV/°C
Thermal Resistance Junction to Solder Point	Rth	11	°C/W
Electrostatic Discharge	ESD	2000	V
Operating Temperature	T _{OPR}	-40~+80	°C
Storage Temperature	Тѕтб	-40~+100	°C
Soldering Temperature	Tsol	260	°C

Electrical & Optical Characteristics (Ta=25°C)

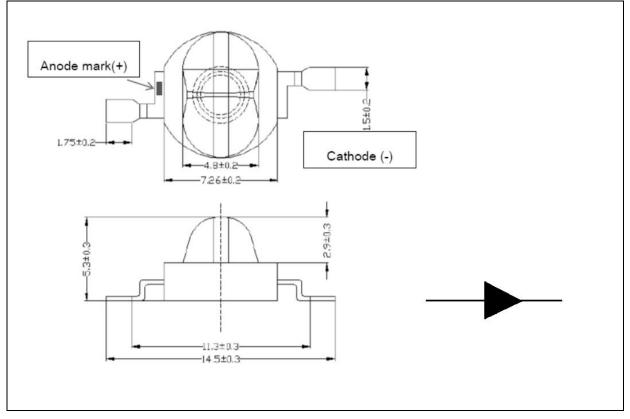
Parameter	Symbol	Values			Unit	Test
Farameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Voltage	VF	1.4		2.4	V	I⊧=200mA
Radiant Power	Po	100	130	190	mW	I _F =200mA
Dominant Wavelength	λ_{D}	840	850	860	nm	I _F =200mA
Viewing Angle	20 _{1/2}		160		deg	I _F =200mA

1. Radiant Power (P_o) ±7%, Forward Voltage (V_F) ±0.05V, Viewing angle(2 $\theta_{1/2}$) ±10°



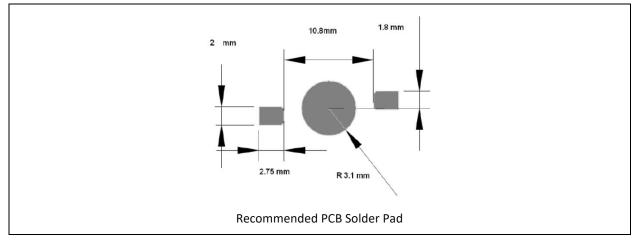
OUTLINE DIMENSION:

Package Dimension:



- 1. All dimensions are in millimetre (mm).
- 2. Tolerance ±0.13mm, unless otherwise noted.

Recommended Soldering Pad Dimension:



1. Dimensions are in millimetre (mm).

3

2. Tolerance ± 0.12 mm with angle tolerance $\pm 0.5^{\circ}$.



BINNING GROUPS:

Code	Min.	Max.	Unit
A	1.6	1.8	
В	1.8	2.0	V
С	2.0	2.2	v
D	2.2	2.4	

Forward Voltage Classifications (I_F = 200mA):

Radiant Power Classifications (I_F = 200mA):

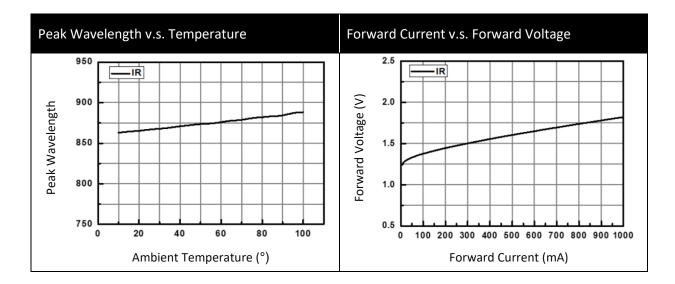
Code	Min.	Max.	Unit
PO1	100	130	
PO2	130	160	mW
PO3	160	190	

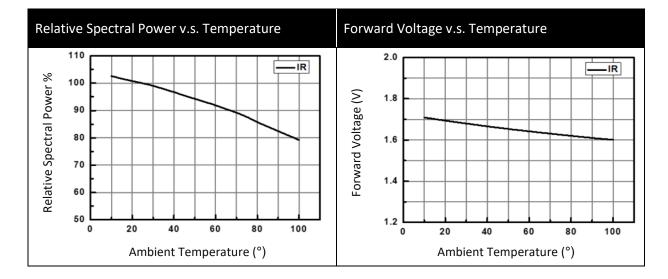
Peak Wavelength Classifications (I_F = 200mA):

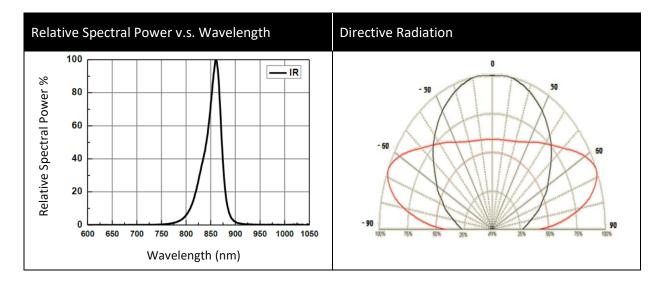
Code	Min.	Max.	Unit
WP1	840	850	
WP2	850	860	nm



ELECTRO-OPTICAL CHARACTERISTICS:



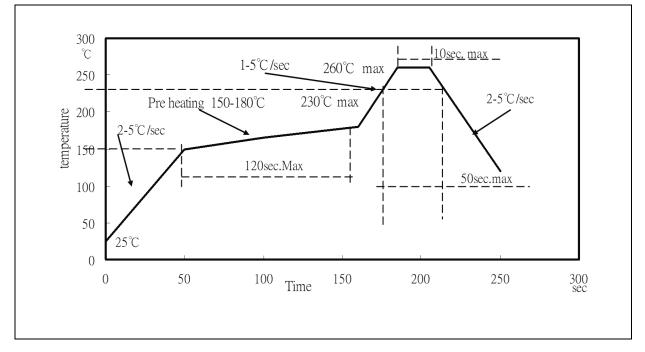






RECOMMENDED SOLDERING PROFILE:

Reflow Lead-free Solder:



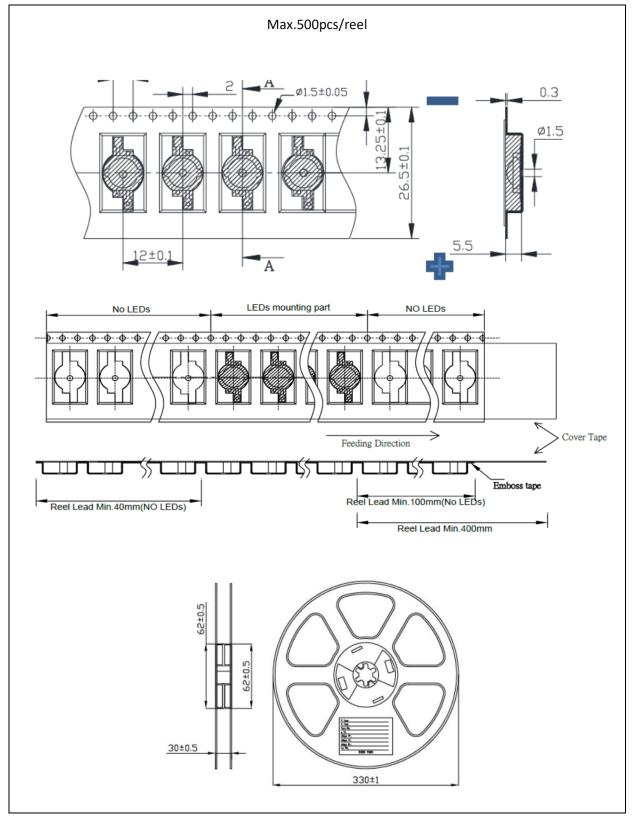
Note:

- 1. Maximum reflow soldering: 2 times.
- 2. Recommended soldering temperature is 245°C. The maximum soldering temperature should be limited to 260°C.
- 3. Before, during, and after soldering, should not apply stress on the components and PCB board.



PACKING SPECIFICATION:

Reel Dimension:



PRECAUTIONS OF USE:



Storage:

It is recommended to store the products in the following conditions:

- Humidity: 60% R.H. Max.
- Temperature: 5°C~30°C (41°F ~86°F).

Shelf life in sealed bag: 12 months at 5°C~30°C and <60% R.H.

Once the package is opened, the products should be used within a week. Otherwise, they should be kept in a damp-proof box with descanting agent <10% R.H. and apply baking before use.

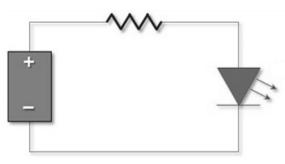
Baking:

It is recommended to bake the LED before soldering if the pack has been unsealed for longer than 24hrs. The suggested baking conditions are as followings:

• 60±3°C x 24hrs and <5%RH, taped / reel package.

It's normal to see slight color fading of carrier (light yellow) after baking in process.

Testing Circuit:



Must apply resistor(s) for protection (over current proof).

Cleaning:

Use alcohol-based cleaning solvents such as isopropyl alcohol to clean the LED carrier / package. Avoid putting any stress force directly on to the LED lens.

ESD (Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing the LED all time. All devices, equipment, machinery, work tables, and storage racks must be properly grounded.

In the events of manual working in process, make sure the devices are well protected from ESD at any time.

8



REVISION RECORD:

Version	Date	Summary of Revision
A1.0	11/09/2020	Datasheet set-up.

9